Technical Program Committee 2017

Chair: Guido Notermans, Nexperia

Advanced CMOS (Analog, Digital) EOS/ESD and Latch-up

Sub-Committee Chair: Robert Gauthier, GLOBALFOUNDRIES

Shih-Hung Chen, imec

Jam-Wem Lee, TSMC

Junjun Li, IBM

Theo Smedes, NXP Semiconductors

Teruo Suzuki, SocioNext

Benjamin Van Camp, Sofics

Yuan Wang, Peking University

Gene Worley, Qualcomm, Inc.

ESD Protection in Bipolar, RF, High Voltage, and BCD Technologies

Sub-Committee Chair: Ann Concannon, Texas Instruments, Inc.

Yiqun Cao, Infineon Technologies

Lin Lin, GLOBALFOUNDRIES

Dimitri Linten, imec

Mototsugu Okushima, Renesas

Nicholas Nolhier, LAAS/CNRS

Javier A. Salcedo, Analog Devices, Inc.

Vladislav Vashchenko, Maxim Integrated Products, Inc.

Carol Rouying Zhan, NXP Semiconductors

Numerical Modeling and Simulation for On-Chip ESD Protection

Sub-Committee Chair: Mayank Shrivastava, Indian Institute of Science

Gianluca Boselli, Texas Instruments, Inc.

Kai Esmark, Infineon Technologies

Steffen Holland, NXP Semiconductors

Nathan Jack, Intel Corporation

You Li, GLOBALFOUNDRIES

Dionyz Pogany, Vienna Technical University

Elyse Rosenbaum, University of Illinois at Urbana-Champaign

Christian Russ, Infineon Technologies

EOS/ESD Failure Analysis, Troubleshooting, and Case Studies

Sub-Committee Chair: Adrien Ille, Infineon Technologies

Dolphin Abessolo-Bidzo, NXP Semiconductors

Marise Bafleur, LAAS/CNRS

Mariano Dissegna, Texas Instruments, Inc.

Tim Iben, IBM

Bart Keppens, Sofics

Manjunatha Prabhu, GLOBALFOUNDRIES

Sandeep Sangameswaran, Philips Semiconductors

Yu-Ti Su, TSMC

Device Testing: Testers, Methods, and Correlation Issues

Sub-Committee Chair: David Eppes, AMD

Michael Chaine, Micron Technology

Thomas Chang, GLOBALFOUNDRIES

Tim Maloney, Center for Analytic Insight

Tom Meuse, Thermo Fisher Scientific

Josh Morris, Intel

Paul Phillips, Phasix ESD

Masanori Sawada. HANWA Electronics

Scott Ward, Texas Instruments, Inc.

System Level EOS/ESD/EMC/HMM

Sub-Committee Chair: Benjamin Orr, Intel Corporation

Robert Ashton, ON Semiconductor

Jeffrey Dunnihoo, Pragma Design

Fabrice Caignet, LAAS/CNRS

Charvaka Duvvury, ESD Consulting LLC

Harald Gossner, Intel Deutschland GmbH

David Johnsson, HPPI

Nathaniel Peachey, Qorvo

Chip/Module/Package EOS/ESD Electronic

Design Automation

Sub-Committee Chair: Michael Khazhinsky, Silicon Laboratories, Inc.

Efraim Aharoni, Tower Semiconductor

Jonathan Brodsky, Texas Instruments, Inc.

Krzysztof Domanski, Intel Deutschland GmbH

Melanie Etherton, NXP Semiconductors

Eleonora Gevinti, STMicroelectronics

Matthew Hogan, Mentor - A Siemens Business

Souvick Mitra, GLOBALFOUNDRIES

Nitesh Trivedi, Intel Corporation

EOS/ESD in Manufacturing

Sub-Committee Co-Chair: Wolfgang Stadler, Intel Deutschland GmbH

Sub-Committee Co-Chair: Michelle Lam, IBM

Cheryl Checketts, ESTATEC

Leo G. Henry, ESD/TLP Consultants

Chuck McClain, Micron Technology

Dale Parkin, Seagate Technology

Jeff Salisbury, Finisar

Jay Skolnik, Skolnik Technical

Matt Strickland, L3 Technologies, Inc.

Scott Ward, Texas Instruments, Inc.

Joshua Yoo, Core Insight, Inc.